SUPERSEDES DATA OF MARCH 1988
NINE WIDE SCHMITT TRIGGER BUFFER/LINE DRIVER; INVERTING

FEATURES

- Schmitt trigger action on all data inputs
- Output capability: standard
- I_{CC} category: MSI

GENERAL DESCRIPTION

The 74HC/HCT9014 are high-speed Si-gate CMOS devices and are pin compatible with low power Schottky TTL (LSTTL). They are specified in compliance with JEDEC standard no. 7A.

The 74HC/HCT9014 are nine wide Schmitt trigger inverting buffer/line drivers with Schmitt trigger inputs. These inputs transform slowly changing input signals into sharply defined jitter-free output signals.

The "9014" is identical to the "9015" but has inverting inputs.

SYMBOL	PARAMETER	CONDITIONS	TYPICAL		UNIT
			HC	HCT	
t_{PHL}/t_{PLH}	propagation delay A_n to $\overline{Y}_n$	C_L = 15 pF; V_{CC} = 5 V	12	13	ns
C_I	input capacitance		3.5	3.5	pF
C_{PD}	power dissipation capacitance per buffer	notes 1 and 2	30	32	pF

GND = 0 V; T_{amb} = 25 °C; $t_r = t_f$ = 6 ns

Notes

1. C_{PD} is used to determine the dynamic power dissipation (P_D in μW):
   $P_D = C_{PD} \times V_{CC}^2 \times f_i + \Sigma (C_L \times V_{CC}^2 \times f_o)$ where:
   f_i = input frequency in MHz
   f_o = output frequency in MHz
   $\Sigma (C_L \times V_{CC}^2 \times f_o)$ = sum of outputs
   C_L = output load capacitance in pF
   V_{CC} = supply voltage in V
2. For HC the condition is V_I = GND to V_{CC}
   For HCT the condition is V_I = GND to V_{CC} − 1.5 V

PACKAGE OUTLINES

20-lead DIL; plastic (SOT146).
20-lead mini-pack; plastic (SO20; SOT163A).

PIN DESCRIPTION

PIN NO.	SYMBOL	NAME AND FUNCTION
1, 2, 3, 4, 5, 6, 7, 8, 9	A_0 to A_8	data inputs
10	GND	ground (0 V)
19, 18, 17, 16, 15, 14, 13, 12, 11	$\overline{Y}_0$ to $\overline{Y}_8$	data outputs
20	V_{CC}	positive supply voltage

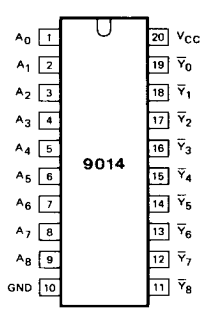

Fig. 1 Pin configuration.

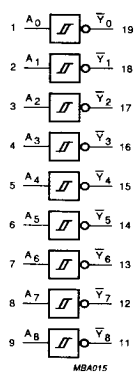

Fig. 2 Logic symbol.

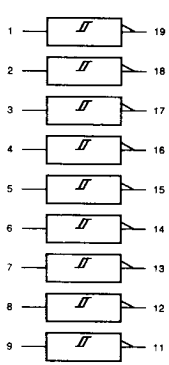

Fig. 3 IEC logic symbol.

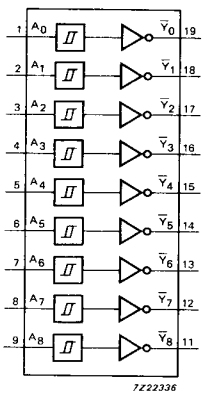

Fig. 4 Functional diagram.

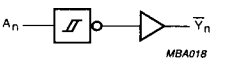

Fig. 5 Logic diagram (one Schmitt trigger).

FUNCTION TABLE

INPUTS	OUTPUTS
A_n	$\overline{Y}_n$
L	H
H	L

H = HIGH voltage level
L = LOW voltage level

DC CHARACTERISTICS FOR 74HC

For the DC characteristics see chapter "HCMOS family characteristics", section "Family specifications".
Transfer characteristics are given below.

Output capability: standard
I_{CC} category: MSI

TRANSFER CHARACTERISTICS FOR 74HC

Voltages are refered to GND (ground = 0 V)

SYMBOL	PARAMETER	T_{amb} (°C)							UNIT	TEST CONDITIONS	
		74HC								V_{CC} V	WAVEFORMS
		+25			−40 to +85		−40 to +125				
		min.	typ.	max.	min.	max.	min.	max.			
V_{T+}	positive-going threshold	0.70 1.75 2.30	1.13 2.37 3.11	1.50 3.15 4.20	0.70 1.75 2.30	1.50 3.15 4.20	0.70 1.75 2.30	1.50 3.15 4.20	V	2.0 4.5 6.0	Figs 6 and 7
V_{T-}	negative-going threshold	0.30 1.35 1.80	0.70 1.80 2.43	1.10 2.40 3.30	0.30 1.35 1.80	1.10 2.40 3.30	0.30 1.35 1.80	1.10 2.40 3.30	V	2.0 4.5 6.0	Figs 6 and 7
V_H	hysteresis ($V_{T+} - V_{T-}$)	0.2 0.4 0.5	0.43 0.57 0.68	0.80 1.00 1.10	0.18 0.40 0.50	0.80 1.00 1.10	0.15 0.40 0.50	0.80 1.00 1.10	V	2.0 4.5 6.0	Figs 6 and 7

AC CHARACTERISTICS FOR 74HC

GND = 0 V; $t_r = t_f$ = 6 ns; C_L = 50 pF

SYMBOL	PARAMETER	T_{amb} (°C)							UNIT	TEST CONDITIONS	
		74HC								V_{CC} V	WAVEFORMS
		+25			−40 to +85		−40 to +125				
		min.	typ.	max.	min.	max.	min.	max.			
t_{PHL}/ t_{PLH}	propagation delay A_n to $\overline{Y}_n$		33 12 10	105 21 18		130 26 22		160 32 27	ns	2.0 4.5 6.0	Fig.8
t_{THL}/ t_{TLH}	output transition time		19 7 6	75 15 13		95 19 16		110 22 19	ns	2.0 4.5 6.0	Fig.8

DC CHARACTERISTICS FOR 74HCT

For the DC characteristics see chapter "HCMOS family characteristics", section "Family specifications".
Transfer characteristics are given below.

Output capability: standard
I_{CC} category: MSI

Note to HCT types

The value of additional quiescent supply current (ΔI_{CC}) for a unit load of 1 is given in the family specifications.
To determine ΔI_{CC} per input, multiply this value by the unit load coefficient shown in the table below.

INPUT	UNIT LOAD COEFFICIENT
A_n	0.3

TRANSFER CHARACTERISTICS FOR 74HCT

Voltages are refered to GND (ground = 0 V)

SYMBOL	PARAMETER	T_{amb} (°C)							UNIT	TEST CONDITIONS	
		74HCT								V_{CC} V	WAVEFORMS
		+25			−40 to +85		−40 to +125				
		min.	typ.	max.	min.	max.	min.	max.			
V_{T+}	positive-going threshold	0.9 1.2	1.50 1.70	2.0 2.1	0.9 1.2	2.0 2.1	0.9 1.2	2.0 2.1	V	4.5 5.5	Figs 6 and 7
V_{T-}	negative-going threshold	0.7 0.8	1.06 1.27	1.4 1.7	0.7 0.8	1.4 1.7	0.7 0.8	1.4 2.7	V	4.5 5.5	Figs 6 and 7
V_H	hysteresis ($V_{T+} - V_{T-}$)	0.2 0.2	0.44 0.44	0.8 0.8	0.2 0.2	0.8 0.8	0.2 0.2	0.8 0.8	V	4.5 5.5	Figs 6 and 7

AC CHARACTERISTICS FOR 74HCT

GND = 0 V; $t_r = t_f$ = 6 ns; C_L = 50 pF

SYMBOL	PARAMETER	T_{amb} (°C)							UNIT	TEST CONDITIONS	
		74HCT								V_{CC} V	WAVEFORMS
		+25			−40 to +85		−40 to +125				
		min.	typ.	max.	min.	max.	min.	max.			
t_{PHL}/ t_{PLH}	propagation delay A_n to $\overline{Y}_n$		19	32		40		48	ns	4.5	Fig.8
t_{THL}/ t_{TLH}	output transition time		7	15		19		22	ns	4.5	Fig.8

TRANSFER CHARACTERISTIC WAVEFORMS

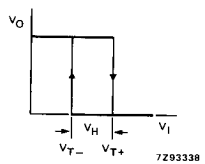

Fig.6 Transfer characteristic.

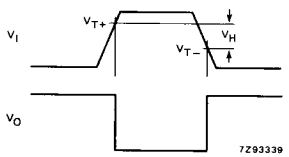

Fig.7 Waveforms showing the definition of V_{T+}, V_{T-} and V_H.

AC WAVEFORMS

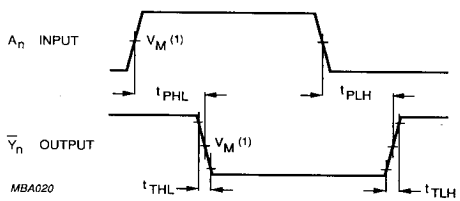

Fig.8 Waveforms showing the input (A_n) to output ($\overline{Y}_n$) propagation delays and the output transition times.

Note to AC waveforms

(1) HC : V_M = 50%; V_I = GND to V_{CC}.
HCT: V_M = 1.3 V; V_I = GND to 3 V.